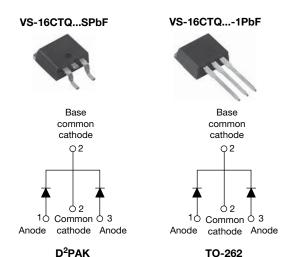
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## High Performance Schottky Rectifier, 2 x 8 A



PRODUCT SUMMARY	
Package	TO-263AB (D <sup>2</sup> PAK), TO-262AA
I <sub>F(AV)</sub>	2 x 8 A
V <sub>R</sub>	60 V, 80 V, 100 V
V <sub>F</sub> at I <sub>F</sub>	0.58 V
I <sub>RM</sub>	7 mA at 125 °C
T <sub>J</sub> max.	175 °C
Diode variation	Common cathode
E <sub>AS</sub>	7.5 mJ

#### **FEATURES**

- 175 °C T<sub>J</sub> operation
- Center tap configuration
- Low forward voltage drop
- High purity, high temperature epoxy encapsulation for enhanced mechanical strength and moisture resistance
- High frequency operation
- Guard ring for enhanced ruggedness and long **FREE** term reliability
- Meets MSL level 1, per J-STD-020, LF maximum peak of 260 °C
- AEC-Q101 qualified
- Material categorization: For definitions of compliance please see <u>www.vishay.com/doc?99912</u>

### DESCRIPTION

This center tap Schottky rectifier series has been optimized for low reverse leakage at high temperature. The proprietary barrier technology allows for reliable operation up to 175 °C junction temperature. Typical applications are in switching power supplies, converters, freewheeling diodes, and reverse battery protection.

MAJOR RATINGS AND CHARACTERISTICS							
SYMBOL	CHARACTERISTICS	VALUES	UNITS				
I <sub>F(AV)</sub>	Rectangular waveform	16	A				
V <sub>RRM</sub>		60 to 100	V				
I <sub>FSM</sub>	t <sub>p</sub> = 5 μs sine	850	A				
V <sub>F</sub>	8 A <sub>pk</sub> , T <sub>J</sub> = 125 °C (per leg)	0.58	V				
TJ	Range	-55 to +175	°C				

VOLTAGE RATINGS					
PARAMETER	SYMBOL	VS-16CTQ060SPbF VS-16CTQ060-1PbF	VS-16CTQ080SPbF VS-16CTQ080-1PbF	VS-16CTQ100SPbF VS-16CTQ100-1PbF	UNITS
Maximum DC reverse voltage	V <sub>R</sub>	60	80	100	V
Maximum working peak reverse voltage	V <sub>RWM</sub>	00	80	100	V

ABSOLUTE MAXIMUM RATINGS							
PARAMETER	SYMBOL	TEST COND	VALUES	UNITS			
Maximum average per leg				8			
forward current per device See fig. 5	I <sub>F(AV)</sub>	$I_{F(AV)}$ 50 % duty cycle at T <sub>C</sub> = 148 °C, rectangular waveform		16	A		
Maximum peak one cycle		5 µs sine or 3 µs rect. pulse	Following any rated load	850			
non-repetitive surge current per leg See fig. 7	I <sub>FSM</sub>	10 ms sine or 6 ms rect. pulse	condition and with rated V <sub>RRM</sub> applied	275	A		
Non-repetitive avalanche energy per leg	E <sub>AS</sub>	$T_J = 25 \ ^{\circ}C, \ I_{AS} = 0.50 \ A, \ L = 60$	) mH	7.50	mJ		
Repetitive avalanche current per leg	I <sub>AR</sub>	Current decaying linearly to zer Frequency limited by T <sub>J</sub> maxim	•	0.50	А		

Revision: 27-Feb-14

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HALOGEN



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ELECTRICAL	SPECIFICATIONS
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PARAMETER	SYMBOL	TEST CO	NDITIONS	VALUES	UNITS
		8 A	T <sub>.1</sub> = 25 °C	0.72	
Maximum forward voltage drop per leg	V <sub>FM</sub> <sup>(1)</sup>	16 A	1j=25 C	0.88	v
See fig. 1	VFM (''	8 A	T = 125 °C	0.58	V
		16 A	T <sub>J</sub> = 125 °C	0.69	
Maximum reverse leakage current per leg	I <sub>RM</sub> <sup>(1)</sup>	T <sub>J</sub> = 25 °C	V <sub>R</sub> = Rated V <sub>R</sub>	0.55	mA
See fig. 2		T <sub>J</sub> = 125 °C		7.0	
Threshold voltage	V <sub>F(TO)</sub>			0.415	V
Forward slope resistance	r <sub>t</sub>	$T_J = T_J maximum$		11.07	mΩ
Maximum junction capacitance per leg	CT	$V_{R} = 5 V_{DC}$ (test signal range	ge 100 kHz to 1 MHz), 25 °C	500	pF
Typical series inductance per leg	L <sub>S</sub>	Measured lead to lead 5 n	nm from package body	8.0	nH
Maximum voltage rate of change	dV/dt	Rated V <sub>R</sub>		10 000	V/µs

#### Note

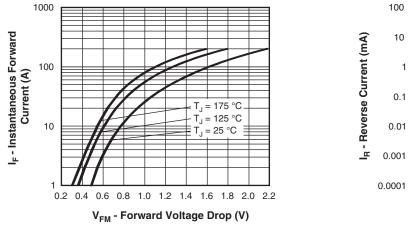
 $^{(1)}\,$  Pulse width < 300  $\mu s,$  duty cycle < 2 %

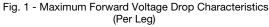
THERMAL - MECHANICAL SPECIFICATIONS					
PARAMETER		SYMBOL	TEST CONDITIONS	VALUES	UNITS
Maximum junction and storage temperature range		T <sub>J</sub> , T <sub>Stg</sub>		-55 to +175	°C
Maximum thermal resistance, junction to case per leg Maximum thermal resistance, junction to case per package		D		3.25	°C/W
		R <sub>thJC</sub>	DC operation	1.63	
Typical thermal resistance, case to heatsink		R <sub>thCS</sub>	Mounting surface, smooth and greased	0.50	
Approvimate weight				2	g
Approximate weight				0.07	oz.
Manuations to service	minimum			6 (5)	kgf∙cm
Mounting torque	maximum			12 (10)	(lbf · in)
Marking device			Case style D <sup>2</sup> PAK	16CT	QS
Marking device			Case style TO-262	16CT0	ຊ1

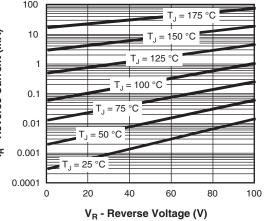


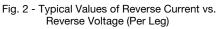
## VS-16CTQ...SPbF, VS-16CTQ...-1PbF Series

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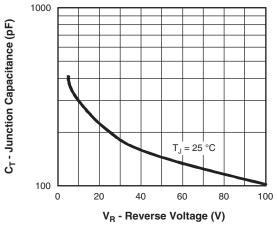


Fig. 3 - Typical Junction Capacitance vs. Reverse Voltage (Per Leg)

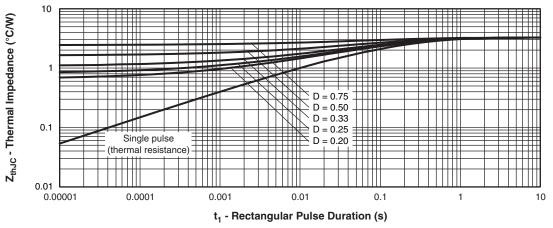
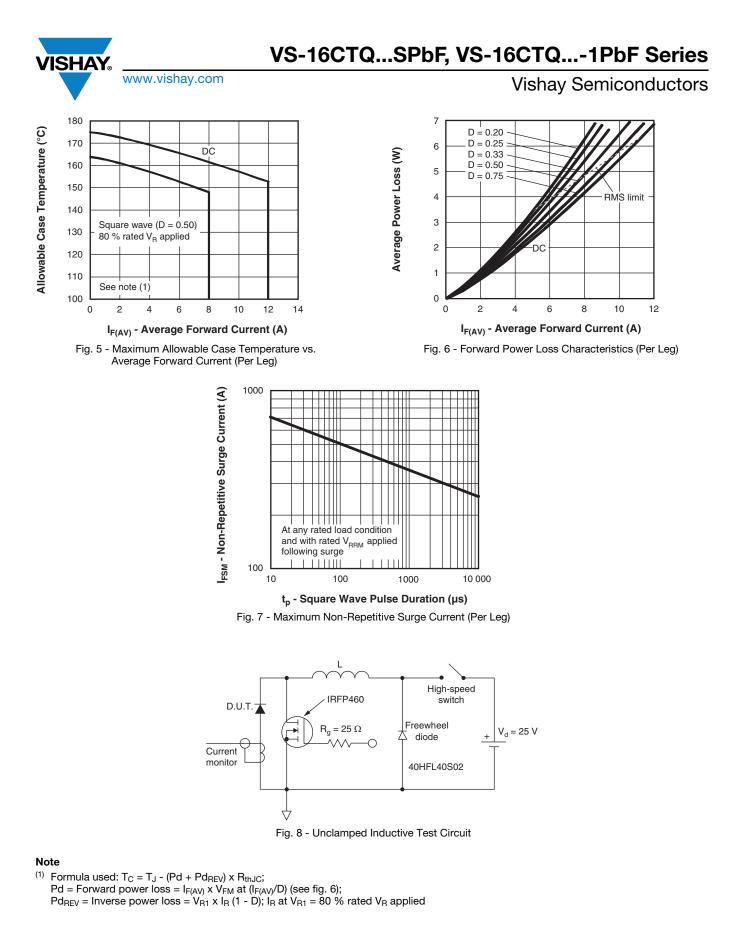


Fig. 4 - Maximum Thermal Impedance Z<sub>thJC</sub> Characteristics (Per Leg)



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Document Number: 94145

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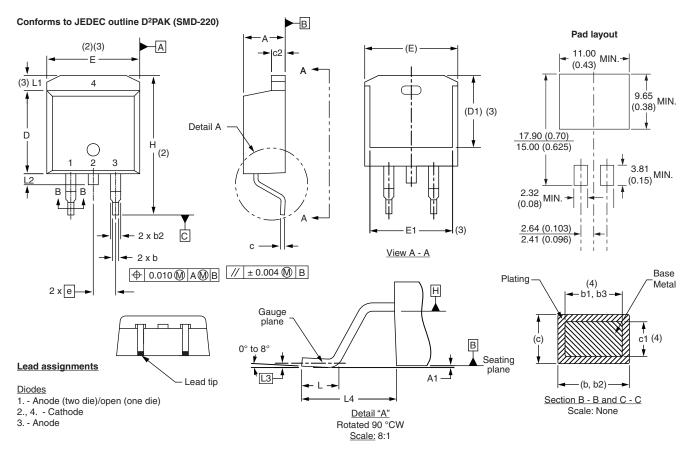
### **ORDERING INFORMATION TABLE**

Device code	VS-	16	С	т	Q	100	s	TRL	PbF
	1	2	3	4	5	6	7	8	9
<ol> <li>Vishay Semiconductors product suffix</li> </ol>									
2 - Current rating (16 A)									
	<ul> <li>Gircuit configuration: C = Common cathode</li> <li>T = TO-220</li> </ul>								
	5 -	Sch	ottky "C	" series			)60 = 60	) V	
	6 -	- Volt	age rati	ngs —			080 = 80		
	7	• S	= D <sup>2</sup> PA	K		1	00 = 10	0 V	
		• -1	= TO-2	62					
	8 -	• N	one = T	ube (50	pieces)				
				pe and i	• •		ed - for [	D <sup>2</sup> PAK (	onlv)
				pe and					• ·
						ni unei	10		( Only)
	9 -	PDF	· = Lead	d (Pb)-fr	ee				

LINKS TO RELAT	ED DOCUMENTS
Dimensions	www.vishay.com/doc?95014
Part marking information	www.vishay.com/doc?95008
Packaging information	www.vishay.com/doc?95032
SPICE model	www.vishay.com/doc?95279

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# D<sup>2</sup>PAK, TO-262



### DIMENSIONS - D<sup>2</sup>PAK in millimeters and inches

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SYMBOL	MILLIN	IETERS	INC	NOTES	
STWIDOL	MIN.	MAX.	MIN.	MAX.	NOTES
А	4.06	4.83	0.160	0.190	
A1	0.00	0.254	0.000	0.010	
b	0.51	0.99	0.020	0.039	
b1	0.51	0.89	0.020	0.035	4
b2	1.14	1.78	0.045	0.070	
b3	1.14	1.73	0.045	0.068	4
с	0.38	0.74	0.015	0.029	
c1	0.38	0.58	0.015	0.023	4
c2	1.14	1.65	0.045	0.065	
D	8.51	9.65	0.335	0.380	2

SYMBOL	MIN.	MAX.	MIN.	MAX.	NOTES
D1	6.86	8.00	0.270	0.315	3
E	9.65	10.67	0.380	0.420	2, 3
E1	7.90	8.80	0.311	0.346	3
е	2.54	BSC	0.100	BSC	
Н	14.61	15.88	0.575	0.625	
L	1.78	2.79	0.070	0.110	
L1	-	1.65	-	0.066	3
L2	1.27	1.78	0.050	0.070	
L3	0.25	BSC	0.010	BSC	
L4	4.78	5.28	0.188	0.208	

INCHES

MILLIMETERS

<sup>(7)</sup> Outline conforms to JEDEC outline TO-263AB

#### Notes

 $^{(1)}\,$  Dimensioning and tolerancing per ASME Y14.5 M-1994  $\,$ 

<sup>(2)</sup> Dimension D and E do not include mold flash. Mold flash shall not exceed 0.127 mm (0.005") per side. These dimensions are measured at the outmost extremes of the plastic body

- $^{(3)}\,$  Thermal pad contour optional within dimension E, L1, D1 and E1
- <sup>(4)</sup> Dimension b1 and c1 apply to base metal only
- <sup>(5)</sup> Datum A and B to be determined at datum plane H
- <sup>(6)</sup> Controlling dimension: inch

Document Number: 95014 Revision: 31-Mar-09

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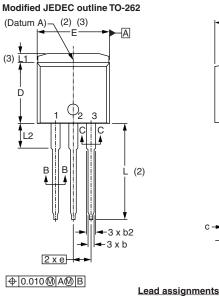
## **Outline Dimensions**

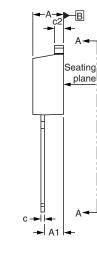
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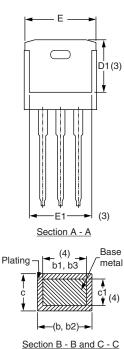
D<sup>2</sup>PAK, TO-262



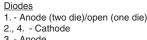
### DIMENSIONS - TO-262 in millimeters and inches

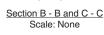






Lead tip





SYMBOL	MILLIN	METERS	INCI	NOTEO	
	MIN.	MAX.	MIN.	MAX.	NOTES
А	4.06	4.83	0.160	0.190	
A1	2.03	3.02	0.080	0.119	
b	0.51	0.99	0.020	0.039	
b1	0.51	0.89	0.020	0.035	4
b2	1.14	1.78	0.045	0.070	
b3	1.14	1.73	0.045	0.068	4
С	0.38	0.74	0.015	0.029	
c1	0.38	0.58	0.015	0.023	4
c2	1.14	1.65	0.045	0.065	
D	8.51	9.65	0.335	0.380	2
D1	6.86	8.00	0.270	0.315	3
E	9.65	10.67	0.380	0.420	2, 3
E1	7.90	8.80	0.311	0.346	3
е	2.54 BSC		0.100	BSC	
L	13.46	14.10	0.530	0.555	
L1	-	1.65	-	0.065	3
L2	3.56	3.71	0.140	0.146	

#### Notes

<sup>(1)</sup> Dimensioning and tolerancing as per ASME Y14.5M-1994

<sup>(2)</sup> Dimension D and E do not include mold flash. Mold flash shall not exceed 0.127 mm (0.005") per side. These dimensions are measured at the outmost extremes of the plastic body

<sup>(3)</sup> Thermal pad contour optional within dimension E, L1, D1 and E1

<sup>(4)</sup> Dimension b1 and c1 apply to base metal only

<sup>(5)</sup> Controlling dimension: inches

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actual package outline

(6) Outline conform to JEDEC TO-262 except A1 (maximum), b (minimum) and D1 (minimum) where dimensions derived the

3. - Anode



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